# NSN 5961-01-289-4238

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# Inclosure Material:

Metal

**Overall Length:** 

1.550 inches

# **Overall Height:**

0.300 inches

**Overall Width:** 

1.050 inches

# Mounting Facility Quantity:

2

#### Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

#### To-3

Electrode Internally-electrically Connected To Case:

Collector

#### Mounting Method:

Unthreaded hole

#### Features Provided:

Hermetically sealed case

#### Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

140.0 collector to base voltage, dc and 140.0 collector-to-emitter, substaining voltage, base open-circuited and 5.0 emitter to base

voltage, static, collector open

#### **Current Rating Per Characteristic:**

20.00 amperes source cutoff current and 5.00 amperes source cutoff current

#### **Power Rating Per Characteristic:**

250.0 watts small-signal input power, common-collector absolute

#### **Transfer Ratio:**

25.0 static forward current transfer ratio, common-emitter and 150.0 static forward current transfer ratio, common-emitter

# Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

# **Special Features:**

Junction pattern arrangement: npn

# Terminal Type And Quantity:

2 pin and 1 case

# Shelf Life:

N/a

# Unit Of Measure:

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#### Demilitarization:

No

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